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Inclosure Material:
Metal
Overall Length:
0.210 inches
Terminal Length:
0.500 inches
Overall Diameter:
Between 0.209 inches and 0.230 inches
Function For Which Designed:
Switching
Internal Configuration:
Junction contact
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
T0-18
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Terminal
Terminal Circle Diameter:
0.100 inches
Features Provided:
Burn in and hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
-15.0 breakdown voltage, collector-to-base, emitter open and -15.0 breakdown voltage, collector-to-emitter, base open and -4.5
breakdown voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
50.00 milliamperes source cutoff current
Power Rating Per Characteristic:
700.0 milliwatts small-signal input power, common-collector preset
Maximum Operating Tempurature Per Measurement Point:
200.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnp
Terminal Type And Quantity:
3 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
-
Demilitarization:
Na

No

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